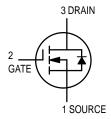
# **TMOS Switching**

# N-Channel — Enhancement



# MPF930 MPF960 MPF990

## **MAXIMUM RATINGS**

Rating	Symbol	MPF930	MPF960	MPF990	Unit
Drain-Source Voltage	V <sub>DS</sub>	35	60	90	Vdc
Drain-Gate Voltage	V <sub>DG</sub>	35	60	90	Vdc
Gate–Source Voltage — Continuous — Non–repetitive ( $t_p \le 50 \mu s$ )	V <sub>GS</sub> V <sub>GSM</sub>		±20 ±40		Vdc Vpk
Drain Current Continuous(1) Pulsed(2)	I <sub>D</sub>	2.0 3.0			Adc
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	PD	1.0 8.0			Watts mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to 150			°C
Thermal Resistance	$\theta_{\sf JA}$	125			°C/W



**ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Drain–Source Breakdown Voltage (V <sub>GS</sub> = 0, I <sub>D</sub> = 10 μAdc)	MPF930 MPF960 MPF990	V(BR)DSX	35 60 90		_ _ _	Vdc
Gate Reverse Current (V <sub>GS</sub> = 15 Vdc, V <sub>DS</sub>	S = 0)	IGSS		_	50	nAdc
ON CHARACTERISTICS(2)						

ON CHARACTERISTICS(2)						
Zero–Gate–Voltage Drain Current (V <sub>DS</sub> = Maximum Rating, V <sub>GS</sub> = 0)		IDSS	_	_	10	μAdc
Gate Threshold Voltage (I <sub>D</sub> = 1.0 mAdc, V <sub>DS</sub> = V <sub>GS</sub> )		VGS(Th)	1.0	_	3.5	Vdc
Drain–Source On–Voltage (V <sub>GS</sub> = 10 Vdc) (I <sub>D</sub> = 0.5 Adc)	MPF930 MPF960 MPF990	VDS(on)		0.4 0.6 0.6	0.7 0.8 1.2	Vdc
(I <sub>D</sub> = 1.0 Adc)	MPF930 MPF960 MPF990		_ _ _	0.9 1.2 1.2	1.4 1.7 2.4	
(I <sub>D</sub> = 2.0 Adc)	MPF930 MPF960 MPF990		_ _ _	2.2 2.8 2.8	3.0 3.5 4.8	

- 1. The Power Dissipation of the package may result in a lower continuous drain current.
- 2. Pulse Test: Pulse Width  $\leq 300 \,\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

## **MPF930 MPF960 MPF990**

# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Тур	Max	Unit
ON CHARACTERISTICS(2) (Continued)						
Static Drain–Source On Resistance (VGS = 10 Vdc, I <sub>D</sub> = 1.0 Adc)	MPF930 MPF960 MPF990	「DS(on)	_ _ _	0.9 1.2 1.2	1.4 1.7 2.0	Ω
On-State Drain Current (V <sub>DS</sub> = 25 Vdc, V <sub>GS</sub> = 10 Vdc)		I <sub>D(on)</sub>	1.0	2.0	_	Amps
SMALL-SIGNAL CHARACTERISTICS				•		•
Input Capacitance ( $V_{DS} = 25 \text{ Vdc}$ , $V_{GS} = 0$ , $f = 1.0 \text{ MHz}$ )		C <sub>iss</sub>	_	70	_	pF
Reverse Transfer Capacitance (V <sub>DS</sub> = 25 Vdc, V <sub>GS</sub> = 0, f = 1.0 MHz)		C <sub>rss</sub>	_	20	_	pF
Output Capacitance (V <sub>DS</sub> = 25 Vdc, V <sub>GS</sub> = 0, f = 1.0 MHz)		C <sub>oss</sub>	_	49	_	pF
Forward Transconductance (V <sub>DS</sub> = 25 Vdc, I <sub>D</sub> = 0.5 Adc)		9fs	200	380	_	mmhos
SWITCHING CHARACTERISTICS						•
Turn-On Time		ton	_	7.0	15	ns
Turn-Off Time		t <sub>off</sub>		7.0	15	ns

<sup>2.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu s,$  Duty Cycle  $\leq$  2.0%.

## **RESISTIVE SWITCHING**

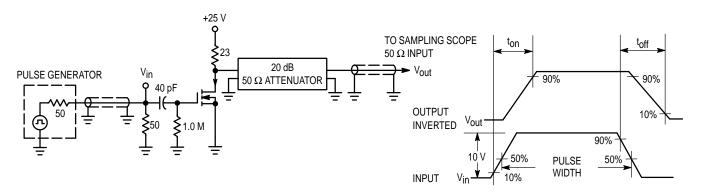


Figure 1. Switching Test Circuit

Figure 2. Switching Waveforms

### **MPF930 MPF960 MPF990**

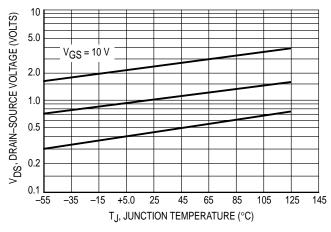


Figure 3. On Voltage versus Temperature

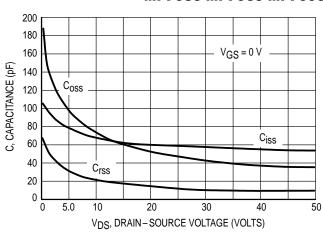


Figure 4. Capacitance Variation

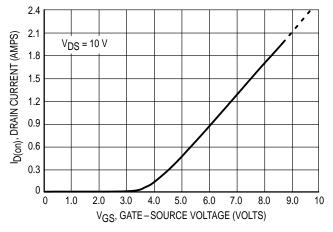


Figure 5. Transfer Characteristic

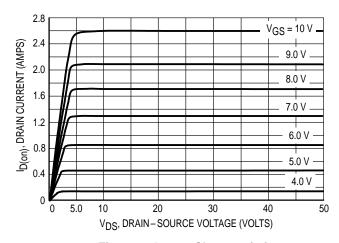


Figure 6. Output Characteristic

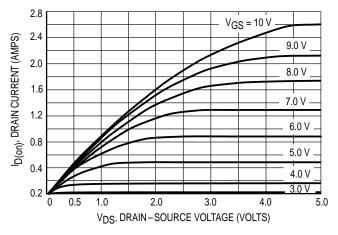
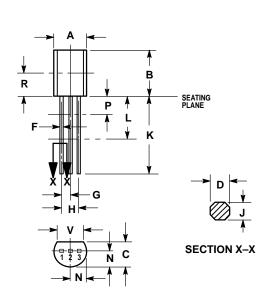


Figure 7. Saturation Characteristic

#### PACKAGE DIMENSIONS



**CASE 029-05** (TO-226AE) **ISSUE AD** 

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND DIMENSION R
   IS UNCONTROLLED.
- 4. DIMENSION F APPLIES BETWEEN P AND L.
  DIMENSIONS D AND J APPLY BETWEEN L AND K
  MIMIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIM	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.44	5.21
В	0.290	0.310	7.37	7.87
С	0.125	0.165	3.18	4.19
D	0.018	0.022	0.46	0.56
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.018	0.024	0.46	0.61
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р	_	0.100	-	2.54
R	0.135		3.43	
٧	0.135		3.43	

STYLE 22: PIN 1. SOURCE

GATE
 DRAIN

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MPF930/D